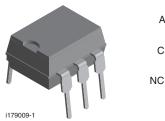
**DESCRIPTION** 

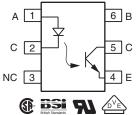
## MOC8101, MOC8102, MOC8103, MOC8104, MOC8105

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# **Optocoupler, Phototransistor Output, no Base Connection**





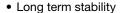
The MOC8101, MOC8102, MOC8103, MOC8104, MOC8105 family optocoupler consisting of a gallium arsenide infrared emitting diode optically coupled to a silicon planar phototransistor detector in a plastic plug-in DIP-6 package.

The coupling device is suitable for signal transmission between two electrically separated circuits. The potential difference between the circuits to be coupled should not exceed the maximum permissible reference voltages.

The base terminal of the MOC8101, MOC8102, MOC8103, MOC8104, MOC8105 is not connected, resulting in a substantially improved common mode interference immunity.

### **FEATURES**

- Isolation test voltage, 5300 V<sub>RMS</sub>
- No base terminal connection for improved common mode interface immunity



- · Industry standard dual in line package
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC





# RoHS

#### **AGENCY APPROVALS**

 UL1577, file no. E52744 system code H or J, double protection

MOC8104-X016

MOC8104-X019T

- CSA 93751
- BSI IEC 60950; IEC 60065

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• DIN EN 60747-5-5 (VDE 0884) available with option 1

ORDERING INFORMATION							
M O C 8 1 0 # - # X 0 # # T  PART NUMBER  CTR PACKAGE OPTION TAPE AND REEL  Option 7 Option 9							
AGENCY CERTIFIED/PACKAGE			CTR (%)				
AGENCT CERTIFIED/FACKAGE	10 mA						
UL, CSA, BSI	50 to 80	73 to 117	108 to 173	160 to 256	65 to 133		
DIP-6	MOC8101	MOC8102	MOC8103	MOC8104	MOC8105		
DIP-6, 400 mil, option 6	=	MOC8102-X006	-	-	-		
SMD-6, option 9	MOC8101-X009	MOC8102-X009	-	-	-		
VDE, UL, CSA, BSI	50 to 80	73 to 117	108 to 173	160 to 256	65 to 133		
DIP-6	MOC8101-X001	-	MOC8103-X001	-	-		

MOC8102-X016

MOC8102-X017T

#### Note

DIP-6, 400 mil

SMD-6, option 7

SMD-6, option 9

• Additional options may be possible, please contact sales office.

MOC8101-X017T



# MOC8101, MOC8102, MOC8103, MOC8104, MOC8105

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ABSOLUTE MAXIMUM RAT	NGS (T <sub>amb</sub> = 25 °C, unless other	wise specified	)		
PARAMETER	TEST CONDITION SYMBOL		VALUE	UNIT	
INPUT	·		•		
Reverse voltage		V <sub>R</sub>	6.0	V	
Forward continuous current		l <sub>F</sub>	60	mA	
Surge forward current	t ≤ 10 µs	I <sub>FSM</sub>	2.5	Α	
Power dissipation		P <sub>diss</sub>	100	mW	
Derate linearly from 25°C			1.33	mW/°C	
OUTPUT	,		•		
Collector emitter breakdown voltage		BV <sub>CEO</sub>	30	V	
Emitter collector breakdown voltage		BV <sub>ECO</sub>	7.0	V	
Collector current		I <sub>C</sub>	50	mA	
Derate linearly from 25°C			2.0	mW/°C	
Power dissipation		P <sub>diss</sub>	150	mW	
COUPLER	,		•		
Isolation test voltage		V <sub>ISO</sub>	5300	$V_{RMS}$	
O			≥ 7.0	mm	
Creepage distance			8.0 <sup>(2)</sup>	mm	
Olean and distance			≥ 7.0	mm	
Clearance distance			8.0 <sup>(2)</sup>	mm	
Isolation thickness between emitter and detector			≥ 0.4	mm	
Comparative tracking index per DIN IEC 112/VDE 0303, part 1		СТІ	175		
Isolation resistance	V <sub>IO</sub> = 500 V	R <sub>IO</sub>	10 <sup>12</sup>	Ω	
Derate linearly from 25 °C	-	-	3.33	mW/°C	
Total power dissipation		P <sub>tot</sub>	250	mW	
Storage temperature		T <sub>stg</sub>	- 55 to + 150	°C	
Operating temperature		T <sub>amb</sub>	- 55 to + 100	°C	
Junction temperature		T <sub>i</sub>	100	°C	
Soldering temperature (1)	max. 10 s, dip soldering: distance to seating plane ≥ 1.5 mm	T <sub>sld</sub>	260	°C	

#### Notes

<sup>(2)</sup> Applies to wide bending option 6.

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT		<u> </u>			•	<u>'</u>	
Forward voltage	$I_F = 10 \text{ mA}$		$V_{F}$		1.25	1.5	V
Breakdown voltage	$I_R = 10 \mu A$		$V_{BR}$	6.0			V
Reverse current	V <sub>R</sub> = 6.0 V		I <sub>R</sub>		0.01	10	μΑ
Capacitance	$V_R = 0 V, f = 1.0 MHz$		Co		25		pF
Thermal resistance			R <sub>thja</sub>		750		K/W
OUTPUT							
Collector emitter capacitance	$V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ MHz}$		C <sub>CE</sub>		5.2		pF
Collector emitter dark current	$V_{CE} = 10 \text{ V}, T_{amp} = 25 ^{\circ}\text{C}$	MOC8101	I <sub>CEO1</sub>		1.0	50	nA
	V <sub>CE</sub> = 10 V, T <sub>amp</sub> = 100 °C	MOC8102	I <sub>CEO1</sub>		1.0		μA
Collector emitter breakdown voltage	I <sub>C</sub> = 1.0 mA		BV <sub>CEO</sub>	30			V
Emitter collector breakdown voltage	$I_E = 100 \mu A$		BV <sub>ECO</sub>	7.0			V
Thermal resistance			R <sub>thja</sub>		500		K/W
COUPLER							
Saturation voltage collector emitter	$I_F = 5.0 \text{ mA}$		V <sub>CEsat</sub>		0.25	0.4	V
Coupling capacitance			C <sub>C</sub>		0.6		pF

#### Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

# MOC8101, MOC8102, MOC8103, MOC8104, MOC8105

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CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Current transfer ratio	V <sub>CE</sub> = 10 V, I <sub>F</sub> = 10 mA	MOC8101	CTR	50		80	%	
		MOC8102	CTR	73		117	%	
		MOC8103	CTR	108		173	%	
		MOC8104	CTR	160		256	%	
		MOC8105	CTR	65		133	%	

<b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	CONDITION SYMBO MIN. TYP.		MAX.	UNIT			
Turn-on time	$V_{CC}$ = 10 V, $I_{C}$ = 2.0 mA, $R_{L}$ = 100 $\Omega$	t <sub>on</sub>		3.0		μs		
Turn-off time	$V_{CC}$ = 10 V, $I_{C}$ = 2.0 mA, $R_{L}$ = 100 $\Omega$	t <sub>off</sub>		2.3		μs		
Rise time	$V_{CC}$ = 10 V, $I_{C}$ = 2.0 mA, $R_{L}$ = 100 $\Omega$	t <sub>r</sub>		2.0		μs		
Fall time	$V_{CC}$ = 10 V, $I_{C}$ = 2.0 mA, $R_{L}$ = 100 $\Omega$	t <sub>f</sub>		2.0		μs		
Cut off frequency		f <sub>co</sub>		250		kHz		

### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

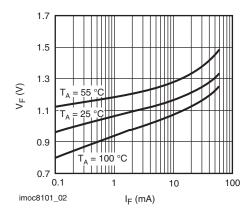


Fig. 1 - Forward Voltage vs. Forward Current

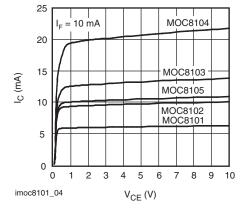


Fig. 3 - Collector Current vs. Collector Emitter Voltage

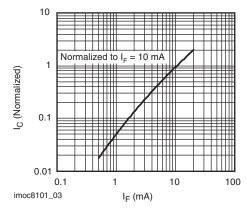


Fig. 2 - Collector Current vs. LED Forward Current

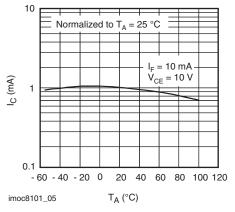


Fig. 4 - Collector Current vs. Ambient Temperature

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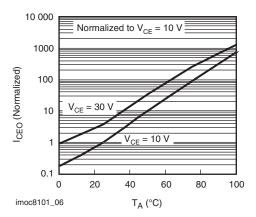


Fig. 5 - Collector Emitter Dark Current vs. Ambient Temperature

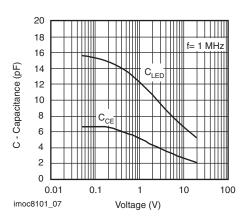


Fig. 6 - Capacitance vs. Voltage

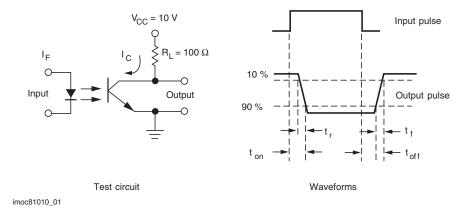


Fig. 7 - Switching Time Test Circuit and Waveforms

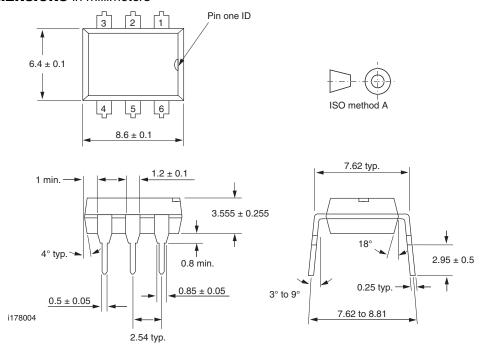


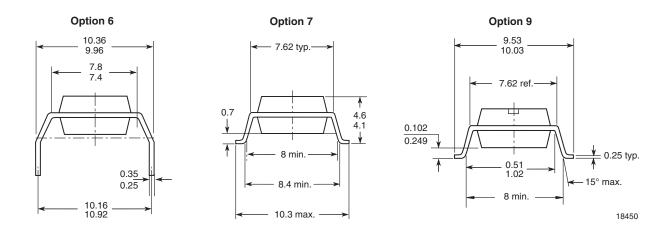
# MOC8101, MOC8102, MOC8103, MOC8104, MOC8105

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### **PACKAGE DIMENSIONS** in millimeters

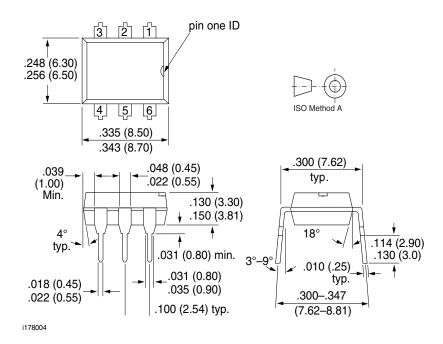








## **Package Dimensions in Inches (mm)**



## **Vishay Semiconductors**



## Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

### We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

> Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423

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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000



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### Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
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- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор оптимального решения, техническое обоснование при выборе компонента;
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- Консультации по применению компонента;
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- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



### Как с нами связаться

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